NSN 5961-01-090-4003

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-090-4003 **Inclosure Material:** Metal **Overall Length:** Between 1.103 inches and 1.107 inches **Overall Height:** Between 0.250 inches and 0.340 inches Overall Width: 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-66 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 70.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 4.00 amperes zero-gate-voltage source current blank **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No